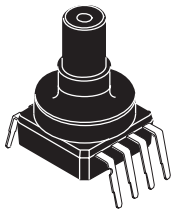
Integrated Silicon Pressure Sensor On-Chip Signal Conditioned, Temperature Compensated and Calibrated

MPVZ5050G SERIES

INTEGRATED PRESSURE SENSOR
0 to 50 kPa (0 to 7.25 psi)
0.2 to 4.7 V Output

SMALL OUTLINE PACKAGE



MPVZ5050GW7U
CASE 1560-02

The MPVZ5050G series piezoresistive transducer is a state-of-the-art monolithic silicon pressure sensor designed for a wide range of applications, but particularly those employing a microcontroller or microprocessor with A/D inputs. This patented, single element transducer combines advanced micromachining techniques, thin-film metallization, and bipolar processing to provide an accurate, high level analog output signal that is proportional to the applied pressure.

Features

- 2.5% Maximum Error over 0° to 85°C
- Ideally suited for Microprocessor or Microcontroller-Based Systems
- Temperature Compensated Over –40° to +125°C
- Patented Silicon Shear Stress Strain Gauge

ORDERING INFORMATION					
Device Type	**Options**	**Case No.**	**MPX Series Order No.**	**Packing Options**	**Device Marking**
SMALL OUTLINE PACKAGE (MPVZ5050G SERIES)					
Ported Elements	Axial Port	1560	MPVZ5050GW7U	Rails	MZ5050GW

SMALL OUTLINE PACKAGE PIN NUMBERS(1)			
1	N/C	5	N/C
2	V_S	6	N/C
3	Gnd	7	N/C
4	V_{out}	8	N/C

1. Pins 1, 5, 6, 7, and 8 are internal device connections. Do not connect to external circuitry or ground. Pin 1 is noted by the notch in the lead.

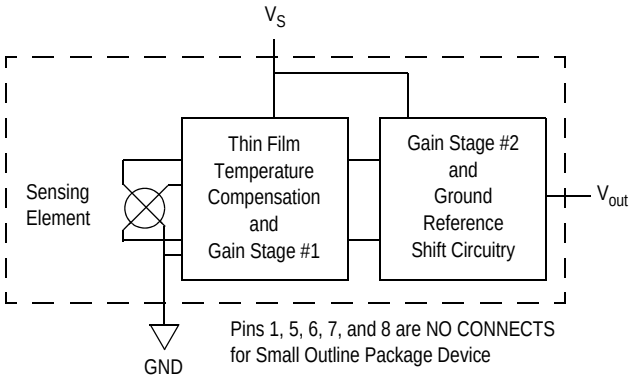


Figure 1. Fully Integrated Pressure Sensor Schematic

Table 1. Maximum Ratings[1]

Rating	Symbol	Value	Unit
Maximum Pressure (P1 > P2)	P_{max}	200	kPa
Storage Temperature	T_{stg}	–40° to +125°	°C
Operating Temperature	T_A	–40° to +125°	°C

1. Exposure beyond the specified limits may cause permanent damage or degradation to the device.

Table 2. . Operating Characteristics (V_S = 5.0 Vdc, T_A = 25°C unless otherwise noted, P1 > P2. Decoupling circuit shown in Figure 4 required to meet electrical specifications.)

Characteristic		Symbol	Min	Typ	Max	Unit
Pressure Range[1]		P_{OP}	0	—	50	kPa
Supply Voltage[2]		V_S	4.75	5.0	5.25	Vdc
Supply Current		I_o	—	7.0	10	mAdc
Minimum Pressure Offset[3] @ V_S = 5.0 Volts	(0 to 85°C)	V_{off}	0.088	0.2	0.313	Vdc
Full Scale Output[4] @ V_S = 5.0 Volts	(0 to 85°C)	V_{FSO}	4.587	4.7	4.813	Vdc
Full Scale Span[5] @ V_S = 5.0 Volts	(0 to 85°C)	V_{FSS}	—	4.5	—	Vdc
Accuracy[6]	(0 to 85°C)	—	—	—	±2.5	$\%V_{FSS}$
Sensitivity		V/P	—	90	—-	mV/kPa
Response Time[7]		t_R	—	1.0	—-	ms
Output Source Current at Full Scale Output		I_{o+}	—	0.1	—-	mAdc
Warm-Up Time[8]		—	—	20	—-	ms
Offset Stability[9]		—	—	±0.5	—-	$\%V_{FSS}$

1. 1.0 kPa (kiloPascal) equals 0.145 psi.
2. Device is ratiometric within this specified excitation range.
3. Offset (V_{off}) is defined as the output voltage at the minimum rated pressure.
4. Full Scale Output (V_{FSO}) is defined as the output voltage at the maximum or full rated pressure.
5. Full Scale Span (V_{FSS}) is defined as the algebraic difference between the output voltage at full rated pressure and the output voltage at the minimum rated pressure.
6. Accuracy (error budget) consists of the following:
   - Linearity: Output deviation from a straight line relationship with pressure over the specified pressure range.
   - Temperature Hysteresis: Output deviation at any temperature within the operating temperature range, after the temperature is cycled to and from the minimum or maximum operating temperature points, with zero differential pressure applied.
   - Pressure Hysteresis: Output deviation at any pressure within the specified range, when this pressure is cycled to and from the minimum or maximum rated pressure at 25°C.
   - TcSpan: Output deviation over the temperature range of 0° to 85°C, relative to 25°C.
   - TcOffset: Output deviation with minimum pressure applied, over the temperature range of 0° to 85°C, relative to 25°C.
   - Variation from Nominal: The variation from nominal values, for Offset or Full Scale Span, as a percent of V_{FSS} at 25°C.
7. Response Time is defined as the time for the incremental change in the output to go from 10% to 90% of its final value when subjected to a specified step change in pressure.
8. Warm-up Time is defined as the time required for the product to meet the specified output voltage after the Pressure has been stabilized.
9. Offset Stability is the product's output deviation when subjected to 1000 hours of Pulsed Pressure, Temperature Cycling with Bias Test.

Figure 3 illustrates the Differential/Gauge Sensing Chip in the basic chip carrier (Case 482A). A fluorosilicone gel isolates the die surface and wire bonds from the environment, while allowing the pressure signal to be transmitted to the sensor diaphragm.

The MPVZ5050G series pressure sensor operating characteristics, and internal reliability and qualification tests are based on use of dry air as the pressure media. Media, other than dry air, may have adverse effects on sensor performance and long-term reliability. Contact the factory for information regarding media compatibility in your application.

Figure 2 shows the sensor output signal relative to pressure input. Typical, minimum, and maximum output curves are shown for operation over a temperature range of 0° to 85°C using the decoupling circuit shown in Figure 4. The output will saturate outside of the specified pressure range.

Figure 4 shows the recommended decoupling circuit for interfacing the output of the integrated sensor to the A/D input of a microprocessor or microcontroller. Proper decoupling of the power supply is recommended.

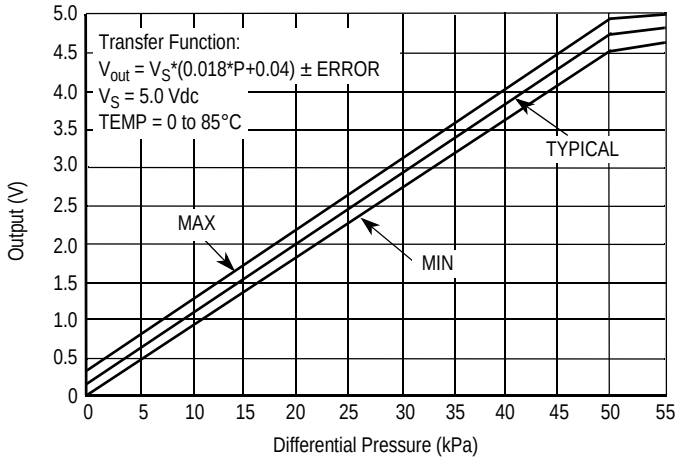


Figure 2. Output versus Pressure Differential

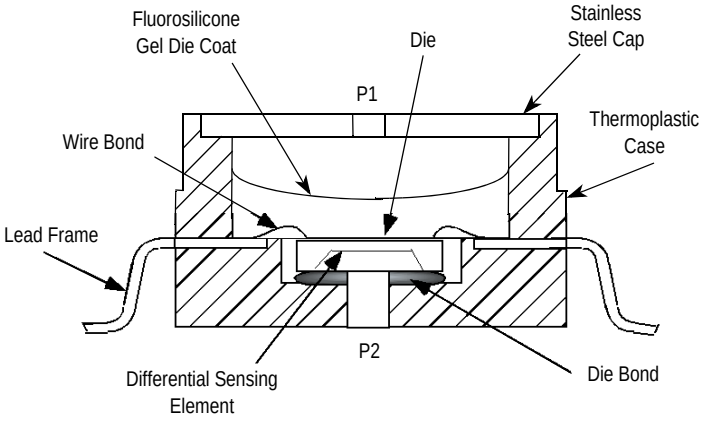


Figure 3. Cross-Sectional Diagram (not to scale)

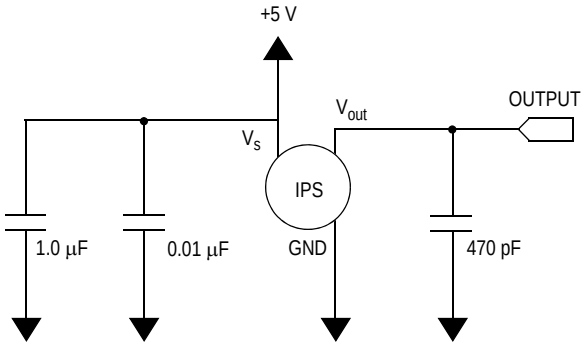


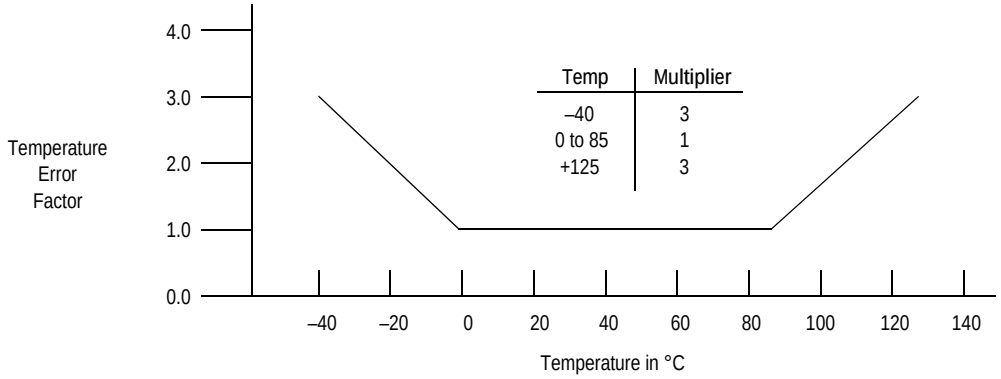
Figure 4. Recommended Power Supply Decoupling and Output Filtering
(For additional output filtering, please refer to Application Note AN1646.)

Transfer Function

Nominal Transfer Value: $V_{out} = V_S (P \times 0.018 + 0.04)$
$\pm$ (Pressure Error x Temp. Factor x 0.018 x V_S)
$V_S = 5.0\ V \pm 0.25$ Vdc

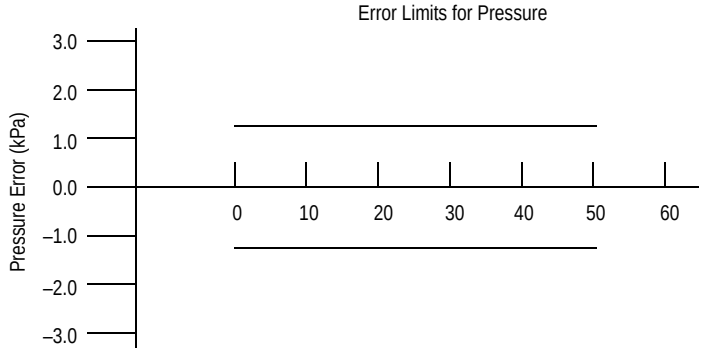
Temperature Error Band

MPVZ5050G SERIES



NOTE: The Temperature Multiplier is a linear response from 0° to –40°C and from 85° to 125°C.

Pressure Error Band



Pressure	Error (Max)
0 to 50 (kPa)	±1.25 (kPa)

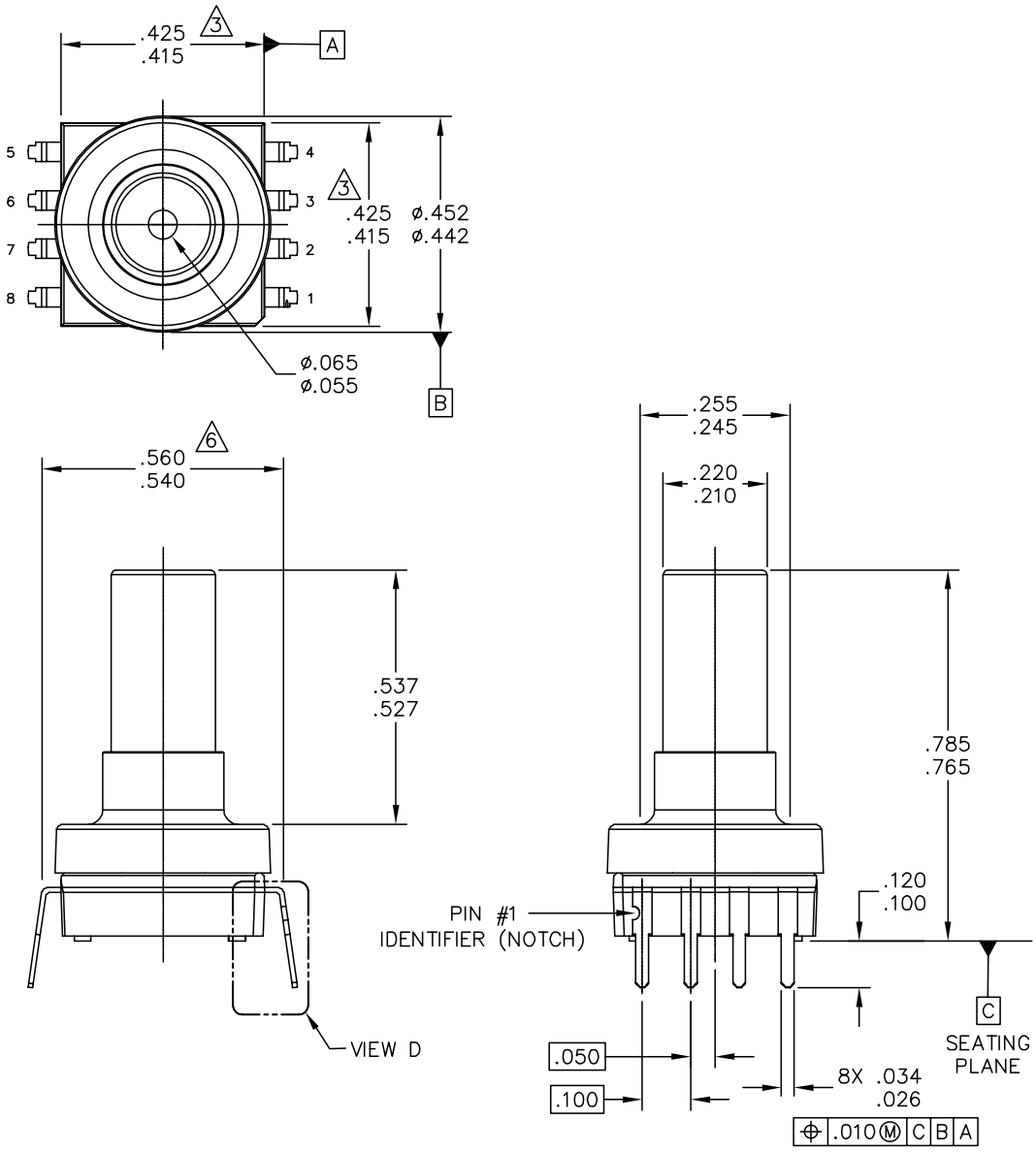
PRESSURE (P1)/VACUUM (P2) SIDE IDENTIFICATION TABLE

Freescale designates the two sides of the pressure sensor as the Pressure (P1) side and the Vacuum (P2) side. The Pressure (P1) side is the side containing fluorosilicone gel which protects the die from harsh media. The MPX pressure sensor is designed to operate with positive differential pressure applied, P1 > P2.

The Pressure (P1) side may be identified by using the table below:

Part Number	Case Type	Pressure (P1) Side Identifier
MPVZ5050GW7U	1560-02	Vertical Port Attached

PACKAGE DIMENSIONS



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	CASE NUMBER: 1560–02	26 MAY 2005
	STANDARD: NON–JEDEC	

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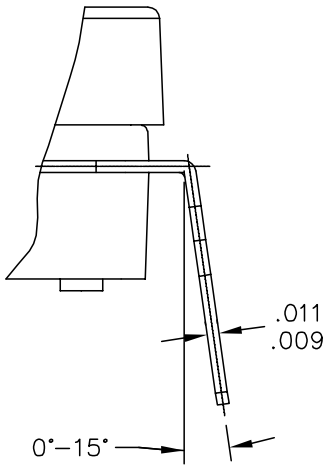
CASE 1560-02
ISSUE C
SMALL OUTLINE PACKAGE

PACKAGE DIMENSIONS



VIEW D

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CASE 1560-02
ISSUE C
SMALL OUTLINE PACKAGE

PACKAGE DIMENSIONS

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M – 1994.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSIONS DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION IS .006.
5. ALL VERTICAL SURFACES 5° TYPICAL DRAFT.
6. DIMENSION TO CENTER OF LEAD WHEN FORMED PARALLEL.

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